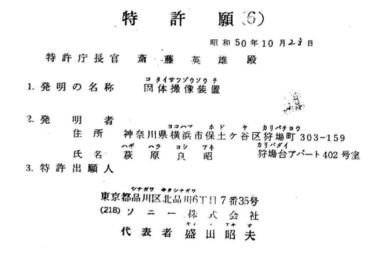
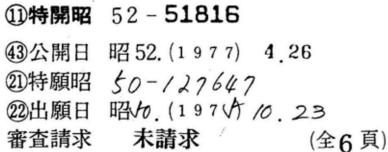
## JPA1975-134985 applied on Nov 10, 1975

Inventor Yoshiaki Hagiwara at Sony

First PNP junction Type
Pinned Buried Photodiode
with the vertical overflow drain (VOD)
and N type Buried Photo Charge Storage
with Completely Empty Potential Well
and Pinned P type Surface with Metal Contact
with Zero RC delay time constant
for high frequency electric shutter function.



## 公開特許公報



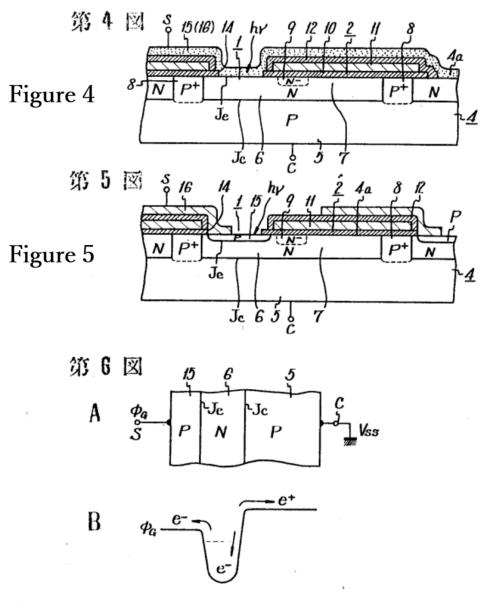


Figure 6 of JPA1975-134985